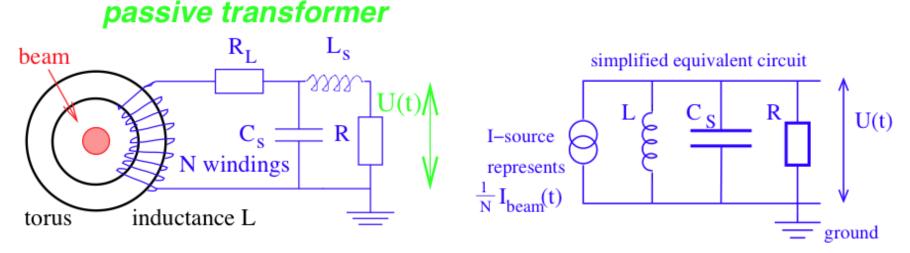


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Simplified electrical circuit of a passively loaded transformer:



A voltages is measured: $U = R \cdot I_{sec} = R / N \cdot I_{beam} \equiv S \cdot I_{beam}$ with *S* sensitivity [V/A], equivalent to transfer function or transfer impedance *Z*.

Equivalent circuit for analysis of sensitivity and bandwidth (disregarding the loss resistivity R_L)

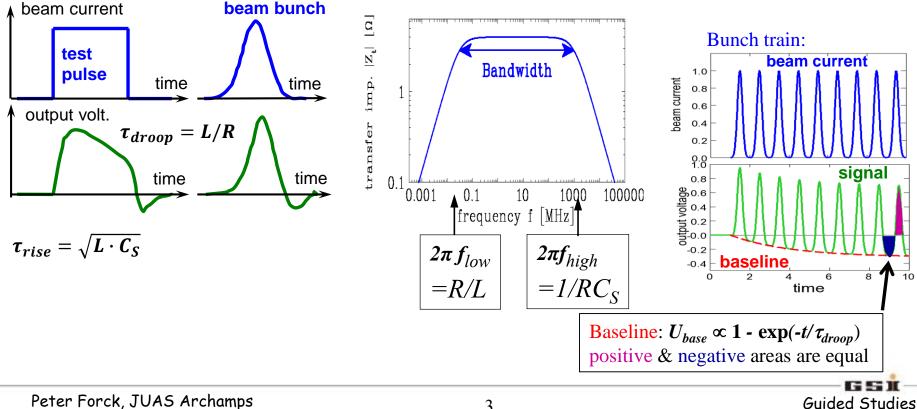
Response of the Passive Transformer: Rise and Droop Time



Time domain description:

Droop time: $\tau_{droop} = 1/(2\pi f_{low}) = L/R$ Rise time: $\tau_{rise} = 1/(2\pi f_{high}) = 1/RC_S$ (ideal without cables) Rise time: $\tau_{rise} = 1/(2\pi f_{high}) = \sqrt{L_s C_s}$ (with cables) R_L : loss resistivity, R: for measuring.

simplified equivalent circuit U(t) I-source represents $\frac{1}{N}I_{\text{beam}}(t)$ ground

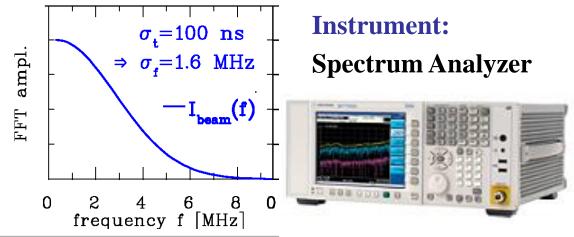


Excurse: Time Domain \leftrightarrow Frequency Domain

Time domain: Recording of a voltage as a function of time:



Frequency domain: Displaying of a voltage as a function of frequency:

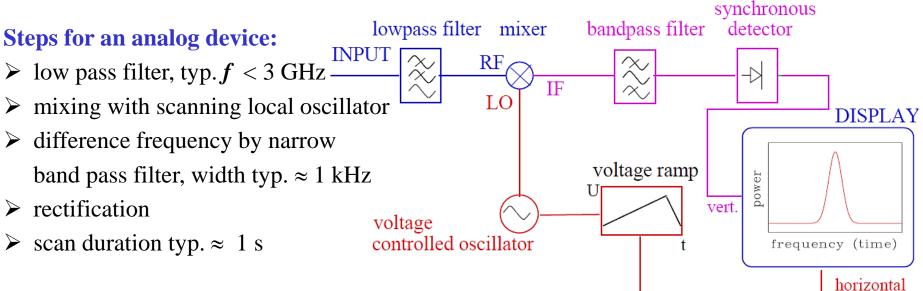


Fourier Transformation of time domain data <u>Care:</u> Contains amplitude <u>and</u> phase

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Excurse: Spectrum Analyzer

The spectrum analyzer determines the frequency spectrum of a signal:



Digital analyzer as modern devices:

- ➢ down mixing typ. 0 100 MHz
- digitalization with 100 MSa/s high resolution 16 bit ADC
- calculation of FFT and versatile display possibilities





Exercise #2: Transformers for a pulsed LINAC 1/3

Assume a beam with 1 ms macro-pulse length at a LINAC

The current should be measured by a current transformer

The maximum droop should be 3% within 1 ms.

Calculate the required droop time constant and the lower cut-off frequency f_{low} ! **Result:** $U(t) = U_0 \cdot e^{-t/\tau_{droop}}$ for t = 1 ms $\frac{U(t)}{U_0} = e^{-1 \text{ ms}/\tau_{droop}} = 0.97 \Rightarrow \tau_{droop} = 32$ ms cut-off frequency: $f_{low} = \frac{1}{2\pi\tau_{droor}} = 4.9 \text{ Hz}$ Core size: $r_i = 30$ mm, $r_o = 60$ mm, length l = 40 mm Permeability of the core: $\mu_r = 10^5 (\mu_0 = 4\pi \cdot 10^{-7} \text{ Vs/Am})$ **Passive transformer** with $\mathbf{R} = 1 \text{ k}\Omega$ termination, $\mathbf{R}_{\mathbf{L}} = 10 \Omega$ loss resistivity Calculate the number of winding for the given droop and the sensitivity [V/A]! Hint: 1 Calculate the required inductance L: $L = \frac{\mu_0 \mu_r}{L} \cdot l \cdot N^2 \cdot \ln \frac{r_o}{L}$ Hint: 1. Calculate the required inductance *L*: 2. The inductance of a core with *N* windings is: **Result:** Inductance via $\tau_{droop} = \frac{L}{R+R_L} \iff L = 33 \text{ Hy} \Rightarrow N = \sqrt{\frac{2\pi L}{\mu\mu_o l \ln r_i/r_o}} = 244$ Sensitivity $S = \frac{U}{L_{harm}} = \frac{R}{N} \approx 4 \text{ V/A}$

General Noise Sources



Guided Studies

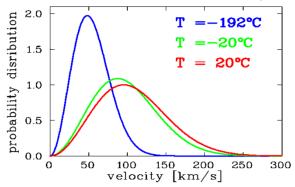
Any electronics is accompanied with noise due to:

Thermal noise as given by the thermal movement of electrons described by Maxwell-Boltzmann distribution Within resistive matter

average movement cancels $U_{mean} = \langle U \rangle = 0$ but standard deviation remains:

 $U_{eff} = \sqrt{\langle U^2 \rangle} = \sqrt{4k_B \cdot T \cdot R \cdot \Delta f}$

Example: Maxwell-Boltzmann distribution of a **free** electron gas



R

at T

this is white noise i.e. no frequency dependence, no dc part

 k_B Boltzmann constant, T temperature, R resistivity, Δf bandwidth

- Shot noise as given by the fluctuations of finite amount of electrons for most electronics not important due to large amount of electrons
- Flicker noise or '1/f noise' as given by trapping of electrons in matter pink noise due to a frequency, 'corner-frequency' $f_c \approx 3$ kHz i.e. 1/f-noise \neq thermal noise

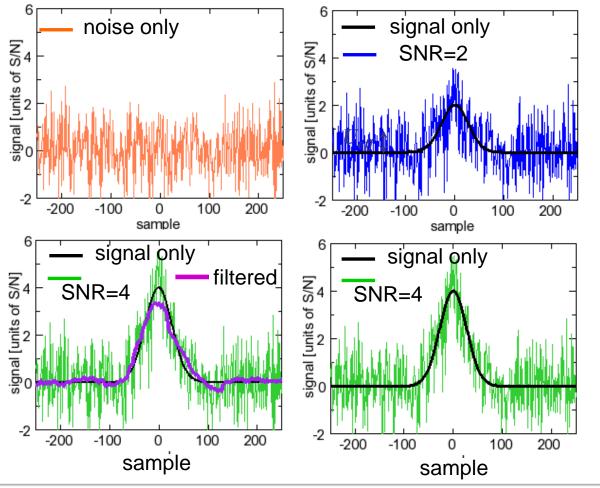
Disturbance by Electro-Magnetic Interference EMI:

Not noise but pick-up of electro-magnetic waves from the environment leads unwanted signal deformation and depends on the surrounding

Maxwell-Boltzmann distribution: $\frac{1}{N} \cdot \frac{dN}{dv} = \frac{4}{\sqrt{\pi}} \left(\frac{m}{3k_BT}\right)^{3/2} \cdot v^2 \cdot \exp\left(-\frac{mv^2}{2k_BT}\right)$

Signal to Noise Consideration

The minimum noise is given thermal noise: $U_{eff} = (4k_BT \cdot R \cdot f)^{1/2}$ R is the input Ohmic resistor \rightarrow low noise amplifier at input stage (realistic 2-3 x U_{eff}) f is the bandwidth of the signal chain



Simulation:

- Broadband 'white' noise
- For Signal-to-Noise = 2 peak just visible
- For Signal-to-Noise = 4 peak well visible
- Filtering improves SNR
 here: n=51 tap moving average
 ⇔ bandwidth restriction

$$y_j^{new} = \frac{1}{n} \cdot \sum_{i=j-n/2}^{i=j+n/2} y_i$$

Guided Studies

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Exercise #2: Transformers for a pulsed LINAC 1/3

Assume a beam with 1 ms macro-pulse length at a LINAC

The current should be measured by a current transformer

The maximum droop should be 3% within 1ms.

Core size: $r_i = 30$ mm, $r_o = 60$ mm, length l = 40 mm Permeability of the core: $\mu_r = 10^5 (\mu_0 = 4\pi \cdot 10^{-7} \text{ Vs/Am})$

Passive transformer with $\mathbf{R} = 1 \text{ k}\Omega$ termination, $\mathbf{R}_{\mathbf{L}} = 10 \Omega$ loss resistivity

The upper cut-off frequency is $f_{high} = 100$ kHz, the lower $f_{low} = 100$ Hz, R is at T=300 K Use $U_{noise} = (4k_B \cdot T \cdot R \cdot \Delta f)^{1/2}$ and $k_B = 1.4 \cdot 10^{-23}$ J/K, bandwidth $\Delta f = f_{high} - f_{low}$

Calculate the thermal noise contribution!

Calculate the threshold concerning the beam current for a signal-to-noise ratio of SNR = 1!

Result: Thermal noise $U_{noise} = \sqrt{4k_BT(R + R_L)\Delta f} = 1.3 \,\mu\text{V}$

Beam current for *S*/*N*=1 : Sensitivity $I_{beam} = \frac{1}{s} \cdot U_{noise} = 0.32 \,\mu\text{A}$

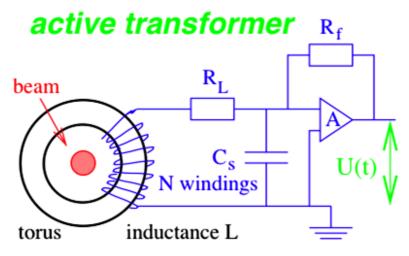
'Active' Transformer with longer Droop Time

Active Transformer or Alternating Current Transformer ACT:

uses a trans-impedance amplifier (I/U converter) to $\mathbf{R} \approx \mathbf{0} \Omega$ load impedance i.e. a current sink

- + compensation feedback
- \Rightarrow longer droop time τ_{droop}

Application: measurement of longer $t > 10 \ \mu s$ e.g. at pulsed LINACs



The input resistor is for an op-amp: $R_{f}/A \ll R_{L}$

$$\Rightarrow \tau_{droop} = L/(R_f/A + R_L) \simeq L/R_L$$

Droop time constant can be up to 1 s!

The feedback resistor is also used for range switching.

An additional active feedback loop is used to compensate the droop.

Operational Amplifier Principle

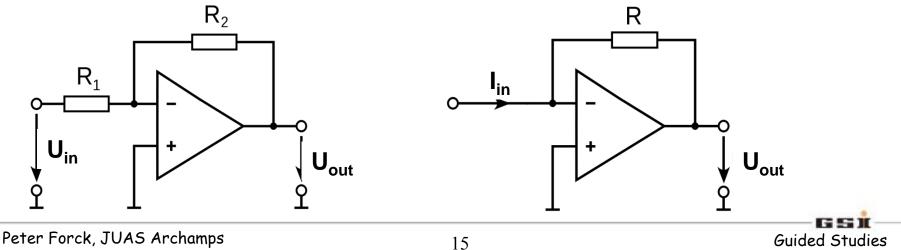
Operational Amplifier: Chips used as a simple equivalent circuit, but has complex built-in electronics

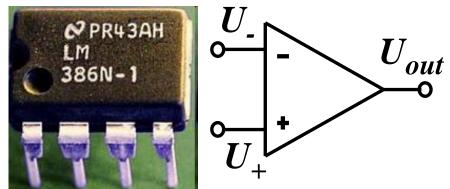
Without feedback: $U_{out} = g_{ol} \cdot (U_+ - U_-)$ Open loop gain: $g_{ol} \approx 10^4$ With feedback: compensation of both inputs

Examples of applications:

- > Inverting voltage amplifier: $U_{out} = g \cdot U_{in} = -R_2 / R_1 \cdot U_{in}$
- > Current-to-voltage converter: $U_{out} = -R \cdot I_{in}$

i.e. feedback leads current sink at inverting input



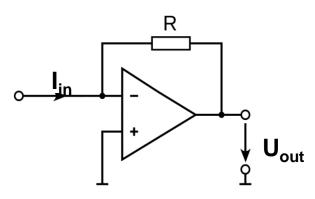


Excurse: Transimpedance Amplifier = I/U Converter

Current-to-voltage converter: $U_a = -R \cdot I_e \equiv Z_t \cdot I_e$

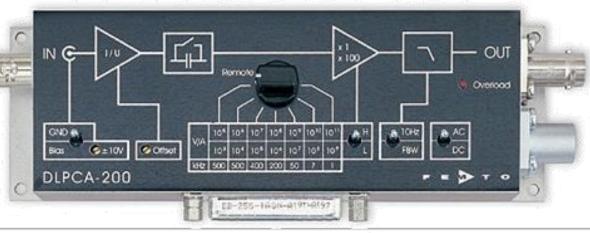
i.e. feedback leads current sink at inverting input

Z_t [V/A]	10 ⁵	107	109	1011
Full scale	100µA	1µA	10nA	100pA
Bandwidth f_{cut} [kHz]	500	400	50	1.1
Risetime <i>t_{rise}</i> 10 to 90%	0.7µs	0.9µs	7µs	300µs
Equivalent noise Noise/full-scale (rel.) Rel.to thermal noise	10nA 10 ⁻⁴ ≈ 1	450pA 2·10 ⁻⁴ ≈ 1	3.7pA 3·10 ⁻⁴ ≈1.6	0.8pA 10 ⁻³ ≈10



Counteraction between➢ Current resolution➢ Time resolution

$$t_{rise} \approx \frac{1}{3 \cdot f_{cut}}$$



Exercise #2: Transformers for a pulsed LINAC 2/3

As for the previous example: Assume a beam with 1 ms macro-pulse length at a LINAC The current should be measured by current transformer Core size: $r_i = 30$ mm, $r_o = 60$ mm, length l = 40 mm Permeability of the core: $\mu_r = 10^5 (\mu_0 = 4\pi \cdot 10^{-7} \text{ Vs/Am})$ The maximum droop should be 3% within 1 ms The upper cut-off frequency is 100 kHz, the resistor is at T = 300 K Active transformer with open-loop ampl. $A = 10^6$ and $R_f = 1$ M Ω feedback, $R_L = 10 \Omega$ Calculate the inductance for the given droop time!

Calculate the number of winding and the sensitivity!

Calculate the threshold concerning the beam current for a signal-to-noise ratio of SNR = 1!

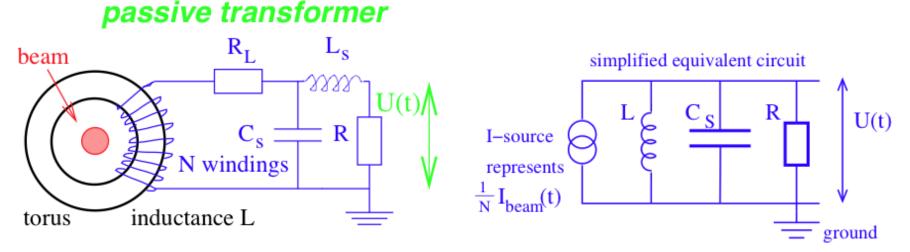
Result: Inductance via $\tau_{droop} = \frac{L}{R_L}$ due to $\frac{R_f}{A} \ll R_L \implies L = 0.32 \ Hy \ \& N = \sqrt{\frac{2\pi L}{\mu \mu_0 l \ln r_i / r_o}} = 24$

Sensitivity
$$S = \frac{R_f}{N} \approx 4.2 \cdot 10^4 \text{ V/A}$$

Noise: $U_{noise} = \sqrt{4k_BT(R_f/A + R_L)\Delta f} = 0.14 \,\mu\text{V}$ & $I_{noise} = \frac{A}{R_f} \cdot U_{noise} = 0.14 \,\mu\text{A}$

Minimum beam current: $I_{beam} = \frac{I_{noise}}{N} = 6$ nA \rightarrow unrealistically low due further noise

Simplified electrical circuit of a passively loaded transformer:



A voltages is measured: $U = R \cdot I_{sec} = R / N \cdot I_{beam} \equiv S \cdot I_{beam}$

with *S* sensitivity [V/A], equivalent to transfer function or transfer impedance *Z*.

Equivalent circuit for analysis of sensitivity and bandwidth (disregarding the loss resistivity R_L)

Exercise #2: Transformers for a pulsed LINAC 3/3

Assume a beam with <u>1 µs pulse length</u> behind a synchrotron to be measured by a transformer Core size: $r_i = 30$ mm, $r_o = 60$ mm, length l = 40mm The maximum droop should be <u>3% within 1 µs</u> Permeability of the core: $\underline{\mu_r} = 10^3$ due to $\mu_r \propto 1/f$ for f > 100 kHz ($\mu_0 = 4\pi \cdot 10^{-7}$ Vs/Am) The upper cut-off frequency is <u>100 MHz</u>, the resistor is at T=300 K

Fast passive transformer with $\underline{R} = 50 \Omega$ termination

- Calculate the droop time and the lower cut-off frequency! Calculate the inductance for the given droop time!
- Calculate the number of winding and the sensitivity!

Calculate the threshold concerning the beam current for a signal-to-noise ratio of SNR = 1!

Result: $U(t) = U_0 \cdot e^{-t/\tau_{droop}}$ for $t = 1 \ \mu s \Rightarrow \frac{U(t)}{U_0} = e^{-1 \ \mu s/\tau_{droop}} = 0.97 \Rightarrow \tau_{droop} = 33 \ \mu s$ cut-off frequency: $f_{low} = \frac{1}{2\pi\tau_{droop}} = 4.9 \ \text{kHz}$ Inductance via $\tau_{droop} = \frac{L}{R+R_L} \Rightarrow L = 1.97 \ Hy \ \& N = \sqrt{\frac{2\pi L}{\mu\mu_0 l \ln r_i/r_0}} = 19 \approx 20$ Sensitivity $S = \frac{R}{N} \approx 2.5 \ \text{V/A}$ Noise: $U_{noise} = \sqrt{4k_BT(R+R_L)\Delta f} = 10 \ \mu \text{V} \Rightarrow \text{min. } I_{beam} = \frac{1}{s} \cdot U_{noise} = 4 \ \mu \text{A}$

Criteria:

- 1. The output voltage is $U \propto 1/N \Rightarrow$ low number of windings for large signal.
- 2. For a low droop, a large inductance *L* is required due to $\tau_{droop} = L/R$:

 $L \propto N^2$ and $L \propto \mu_r \ (\mu_r \approx 10^5 \text{ for amorphous alloy})$.

3. For a large bandwidth the integrating capacitance C_s should be low $\tau_{rise} = \sqrt{L_s C_s}$. **Depending on applications the behavior is influenced by external elements: >Passive transformer:** $R = 50 \Omega$, $\tau_{rise} \approx 1$ ns for short pulses.

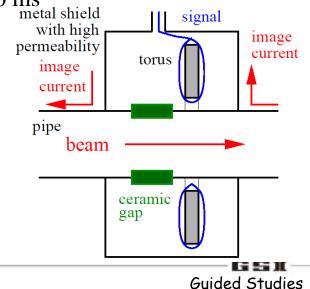
Application: Transfer between synchrotrons : 100 ns $< t_{pulse} < 10 \mu s$

Active transformer: Current sink by I/U-converter, $\tau_{droop} \approx 1$ s for long pulses.

Application: macro-pulses at LINACs : 100 μ s < $t_{pulse} < 10 \text{ ms}_{metal shield}$

General:

- The beam pipe has to be intersected to prevent the flow of the image current through the torus.
- ➤ The torus is made of 25 µm isolated flat ribbon spiraled to get a torus of ≈15 mm thickness, to have large electrical resistivity.
- Additional winding for calibration with current source.



Low Current Measurement for slow Extraction

Slow extraction from synchrotron: lower current compared to LINAC, but higher energies and larger range $R \gg 1$ cm.

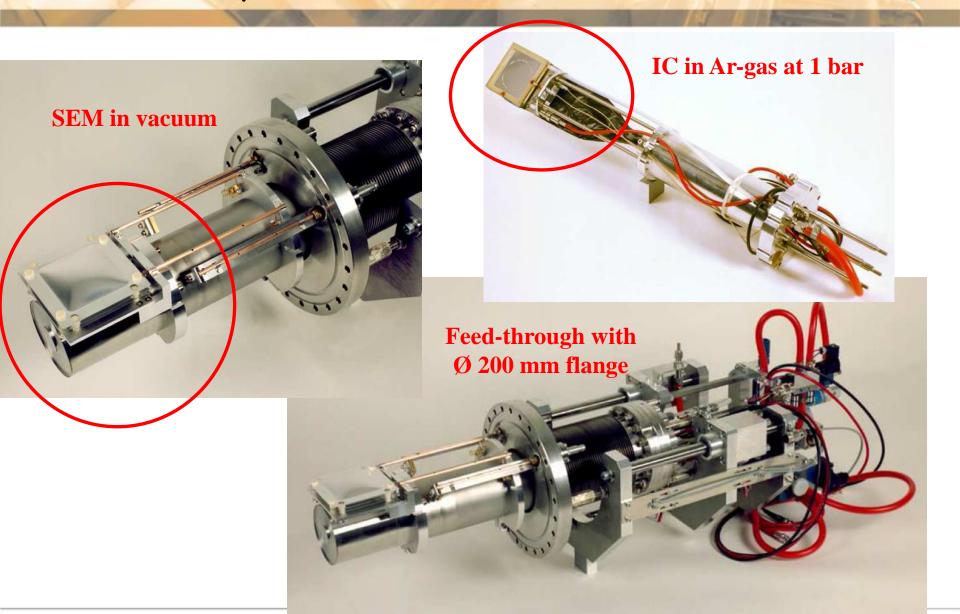
Particle detector technologies for ions of 1 GeV/u, $A = 1 \text{ cm}^2$: U=92 > Particle counting: SEM max: $r \simeq 10^{6} \, 1/s$ \sim **Energy loss in gas (IC):** Φ Charg(min: $I_{sec} \approx 1 \text{ pA}$ max: $I_{sec} \approx 1 \ \mu A$ IC 10 ➢ Sec. e− emission: Nuclear min: $I_{sec} \approx 1 \text{ pA}$ ➤ Max. synch. filling: Scint Space Charge Limit (SCL). p=1 $10^{\overline{3}}$ 10^{5} 10⁹ $10^{11}10^{12}$

10

Guided Studies

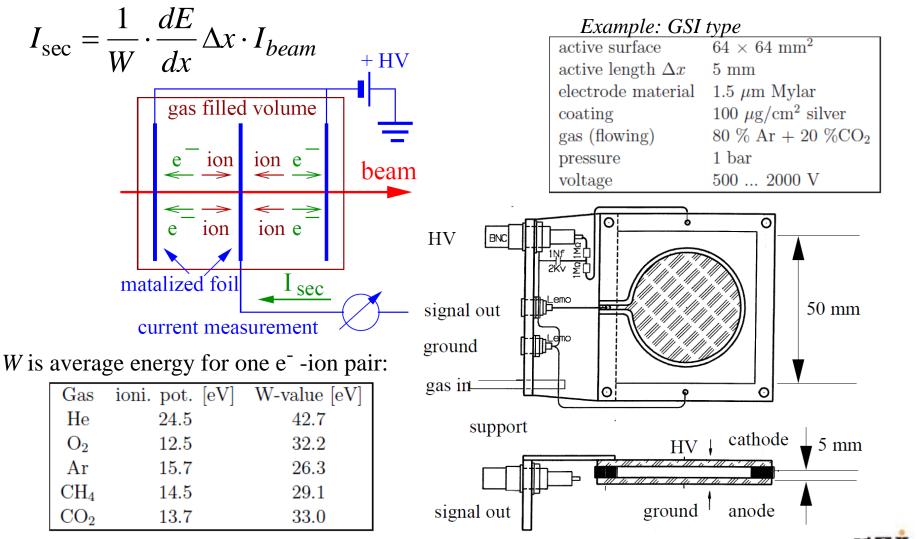
10

Example: GSI Installation for SEM and iC



Ionization Chamber (IC): Electron Ion Pairs

Energy loss of charged particles in gases \rightarrow electron-ion pairs \rightarrow low current meas.



Peter Forck, JUAS Archamps

Assume a beam of $N_i = 1.25 \cdot 10^{12}$ protons extracted from a synchrotron within t = 1 s The current should be measured by an ionization chamber of 0.5cm length filled with Ar The average energy to create a ion-electron pair is W = 26.3 eV

The energy loss is dE/dx = 2.58 keV/cm

Calculate the ion-electron pairs per proton and the secondary current within the IC! The energy loss dE/dx of a proton is $\Delta E_p = \frac{dE}{dx} \cdot \Delta x = 1290 \text{ eV}$ With the average energy for one ion electron pair W, the number of pair is $N_p = \frac{\Delta E_p}{W} = 49$ For the extraction ions N_i per second the amount is $N_{tot} = N_i \cdot N_p/t = 6.1 \cdot 10^{13} \frac{1}{s}$ or a current of $I_e = e \cdot N_{tot} = 9.8 \,\mu\text{A}$. The energy loss (described by Bethe-Bloch equation) scales with $dE/dx \propto Z_n^2$

Assume a beam of $N_i = 1.8 \cdot 10^{10}$ Uranium with $Z_p = 92$ extracted within 1 s

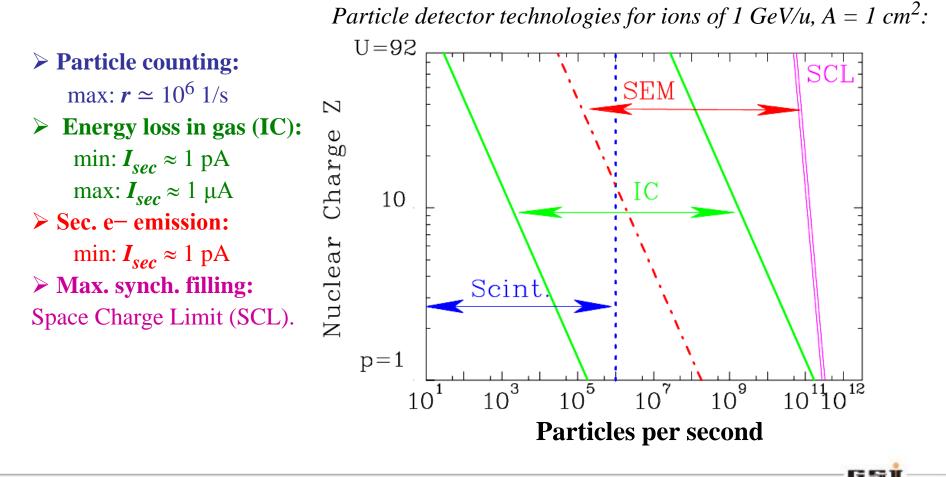
Calculate the ion-electron pair per proton and the secondary current within the IC!

The energy loss per Uranium is $\Delta E_U = (92)^2 \cdot \Delta E_p = 8464 \cdot \Delta E_p = 10.9 \text{ MeV}$

The same calculation as above leads to $I_e = 1.2$ mA i.e. saturation of the IC and a SEM is better!

Low Current Measurement for slow Extraction

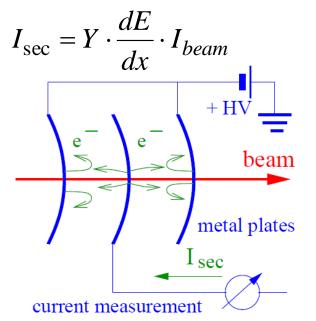
Slow extraction from synchrotron: lower current compared to LINAC, but higher energies and larger range R >> 1 cm.



Secondary Electron Monitor (SEM): Electrons from Surface

For higher intensities SEMs are used.

Due to the energy loss, secondary e⁻ are emitted from a metal surface. The amount of secondary e⁻ is proportional to the energy loss



It is a *surface* effect:

- \rightarrow Sensitive to cleaning procedure
- \rightarrow Possible surface modification by radiation

Example: GSI SEM type

material	pure Al ($\simeq 99.5\%$)
# of electrodes	3
active surface	$80 \times 80 \text{ mm}^2$
distance	$5 \mathrm{mm}$
voltage	100 V

Advantage for Al: good mechanical properties. Disadvantage: Surface effect!

Guided Studies

- e.g. decrease of yield Y due to radiation
- \Rightarrow Ti foils for a permanent insertion.

Sometimes they are installed permanently in front of an experiment.

Assume a beam of $N_i = 1.25 \cdot 10^{12}$ protons extracted from a synchrotron within 1 s The current should be measured by an SEM For Aluminium plates the secondary electron yield is $Y = 27.4 \text{ e}^{-1}/(\text{MeV/mg/cm}^2)$ The energy loss (frequently used units!) is $dE/\rho dx = 1.77 \text{ keV/(mg/cm^2)}$ Calculate the electrons per proton and the secondary current emitted by the SEM! The secondary electrons for one proton is a proton is $I_p = Y \cdot \frac{dE}{odx} = 0..048 e^{-1}$ /ion this corresponds for an extraction N_i proton within t = 1s to a current of $I_e = N_i \cdot I_p = 9.7$ nA The energy loss (described by Bethe-Bloch equation) scales with $dE/dx \propto Z_n^2$ Assume a beam of $N_i = 1.8 \cdot 10^{10}$ Uranium with $Z_p = 92$ extracted within 1 s

Calculate the electron per Uranium and the secondary current by the SEM!

The scaling of the energy loss is $\Delta E_U = (92)^2 \cdot \Delta E_p$

with the number of Uranium per t = 1 s it is $I_e = N_i \cdot I_p = 1.2 \,\mu\text{A}$

Different techniques are suited for different beam parameters:

- e⁻-beam: typically Ø 0.3 to 3 mm, protons: typically Ø 3 to 30 mm
- Intercepting \leftrightarrow non-intercepting methods

Direct observation of electrodynamics processes:

- Synchrotron radiation monitor: non-destructive, only for e⁻-beams, complex
- > OTR screen: nearly non-destructive, large relativistic γ needed, e⁻-beams mainly

Detection of secondary photons, electrons or ions:

- Scintillation screen: destructive, large signal, simple, all beams
- ➢ Ionization profile monitor: non-destructive, expensive, limited resolution, for protons
- Residual fluorescence monitor: non-destructive, limited signal strength, for protons

Wire based electronic methods:

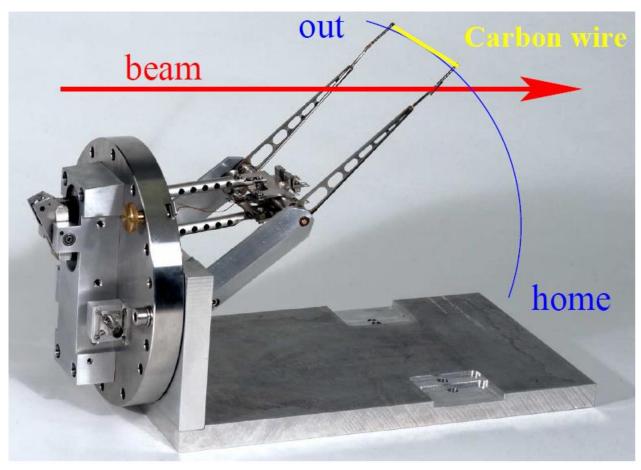
- SEM-grid: partly destructive, large signal and dynamic range, limited resolution
- ➤ Wire scanner: partly destructive, large signal and dynamics, high resolution, slow scan.
- > MWPC-grid: internal amplification, for low current proton-beam.

Exercise #6: Flying Wire for transverse Profile in a Synchrotron

1

Instead of several wires, *one* wire is scanned though the beam.

Fast pendulum scanner for synchrotrons; sometimes it is called '*flying wire*':



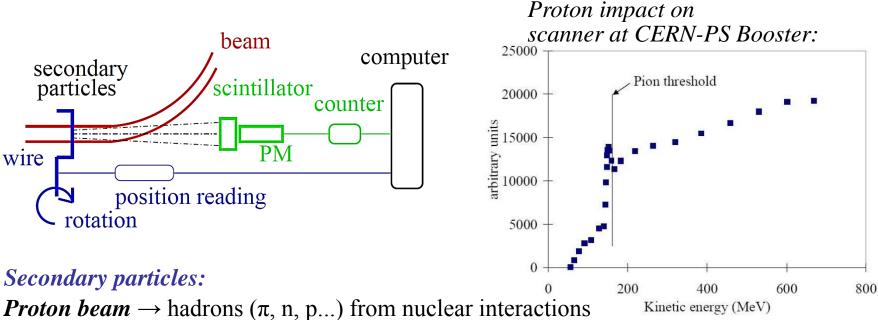


Material: carbon or SiC \rightarrow low Z-material for low energy loss and high temperature. *Thickness*: down to 10 µm \rightarrow high resolution.

Detection: Either the secondary current (like SEM-grid) or

high energy secondary particles (like beam loss monitor)

flying wire: only sec. particle detection due to induced current by movement.



Proton beam \rightarrow hadrons (π , n, p...) from nuclear intera **Electron beam** \rightarrow Bremsstrahlung photons.

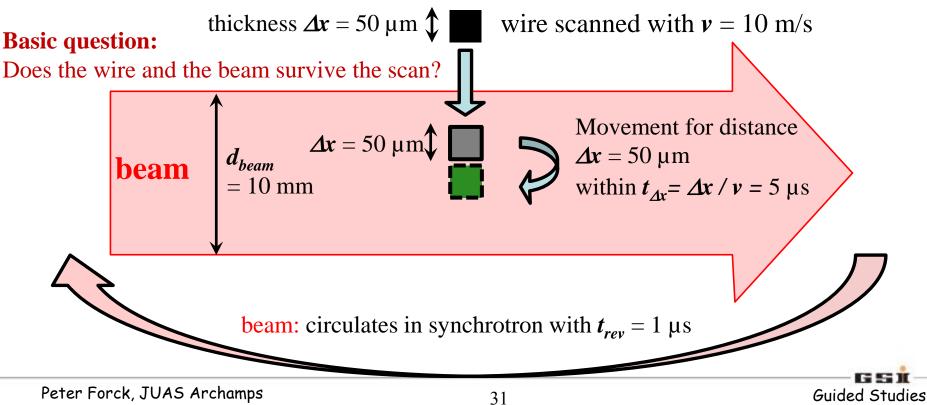
Exercise #6: Transverse profile by flying wire scanner

Assume a beam of 10^{12} protons at 1GeV stored in a synchrotron.

The beam size 10 x 10 mm² with ρ_{beam} =const (for simplification), the revolution time is 1.0 µs. The wire is made of Carbon with 50 x 50 µm² and scanned with v = 10 m/s.

[Carbon is light material of ρ =2.2 g/cm³ density therefore low stopping power.] The energy loss is dE/dx= 4.29 MeV/cm.

Assumptions: rectangular beam and wire, no betatron oscillations.



Exercise #6: Transverse profile by flying wire scanner 1/3



Guided Studies

Assume a beam of 10^{12} protons at 1GeV stored in a synchrotron.

The beam size 10x10 mm with ρ_{beam} =const (for simplification), the revolution time is 1.0 µs. The wire is made of Carbon with 50x50 µm and scanned with *v*=10 m/s.

- [Carbon is light material of ρ =2.2 g/cm³ density therefore low stopping power.]
- The energy loss is dE/dx = 4.29 MeV/cm.
- Calculate the relative energy loss per passage through the wire!
- Calculate the average energy loss during the scan! How many passages an ion does in average? Is this device nearly 'non-destructive' \Leftrightarrow Are the particles lost?

Result: Energy loss for one passage: $\Delta E_{pass} = \frac{dE}{dx} \cdot \Delta x = 0.021$ MeV

time to move by one wire thickness of $\Delta x = 50 \ \mu m$: $t_{\Delta x} = \frac{\Delta x}{v} = 5.0 \ \mu s$

average numbers of passages: $N_{pass} = \frac{t_{\Delta x}}{t_{rev}} = 5$, total time for the scan: $t_{tot} = \frac{d_{beam}}{v} = 1$ ms Proton's energy loss: $\Delta E = N_{pass} \Delta E_{pass} = 0.1$ MeV

 $\Rightarrow \frac{\Delta E}{E_{kin}} = 10^{-4}$ i.e. lower than typical longitudinal acceptance i.e. beam survives

Exercise #6: Transverse profile by flying wire scanner 2/3



Guided Studies

Assume a beam of 10^{12} protons at 1GeV stored in a synchrotron. The beam size 10x10 mm with ρ_{beam} =const (for simplification), the revolution time is 1.0 µs. The wire is made of Carbon with 50x50 µm and scanned with ν =10 m/s. [Carbon is light material of ρ =2.2 g/cm³ density therefore low stopping power.] The energy loss is dE/dx= 4.29 MeV/cm.

Role of thumb: The maximum power rate to prevent for destruction is about 1 W/mm. Is the wire destroyed?

Result: Energy loss for one passage: $\Delta E_{pass} = 0.021$ MeV average numbers of passages: $N_{pass} = \frac{t_{\Delta x}}{t_{rev}} = 5$ Total energy $W = e \cdot \Delta E_{pass} \cdot N_{pass} \cdot N_{stored} = 0.017$ J, total power $P = \frac{W}{t_{tot}} = 17$ W power per mm $P_{mm} = \frac{P}{10 \ mm} = 1.7 \ \frac{W}{mm}$ i.e. on the border \Rightarrow more realistic calculations required

Exercise #6: Transverse profile by flying wire scanner 3/3



Guided Studies

Assume a beam of 10^9 Uranium ions at 1GeV/u stored in a synchrotron.

The beam size 10x10 mm with ρ_{beam} =const (for simplification), the revolution time is 1.0 µs. The wire is made of Carbon with 50x50 µm and scanned with v=10 m/s.

The energy loss is $dE/dx = 3.6 \times 10^4$ MeV/cm (instead of 4.3 MeV/cm for protons).

Why is the energy loss so much larger?

Are the particles loss? Is the wire destroyed? Repeat the same calculation for this case!

Result: Energy loss for one passage: i.e. for Uranium after one passage

out for longitudinal acceptance

 \Rightarrow beam is lost during scan!

Result: Energy deposition in the wire is significantly higher than destruction level \Rightarrow the wire is destroyed!

	р	U
ΔE_{pass} [MeV]	0.021	178
$\Delta E_{pass}/E_{kin}$	$2.1\cdot 10^{-5}$	$7.0\cdot 10^{-4}$

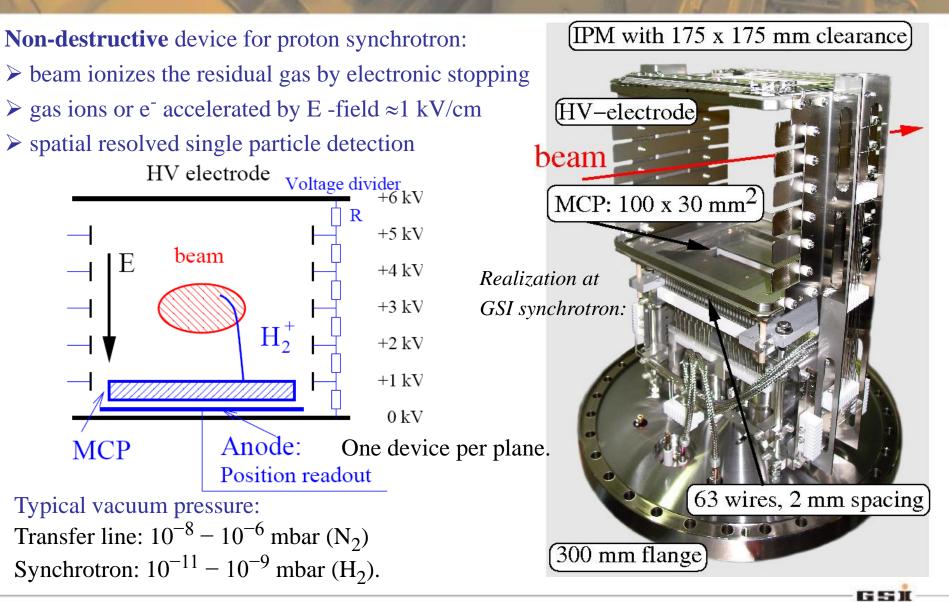
	р	U
W [J]	0.017	0.142
P[W]	17	142
P_{mm} [W/mm]	1.7	14.2

What happens for not fully stripped ions (i.e. ions with some bound electrons)?

What is an appropriate method of profile determination for the Uranium case?

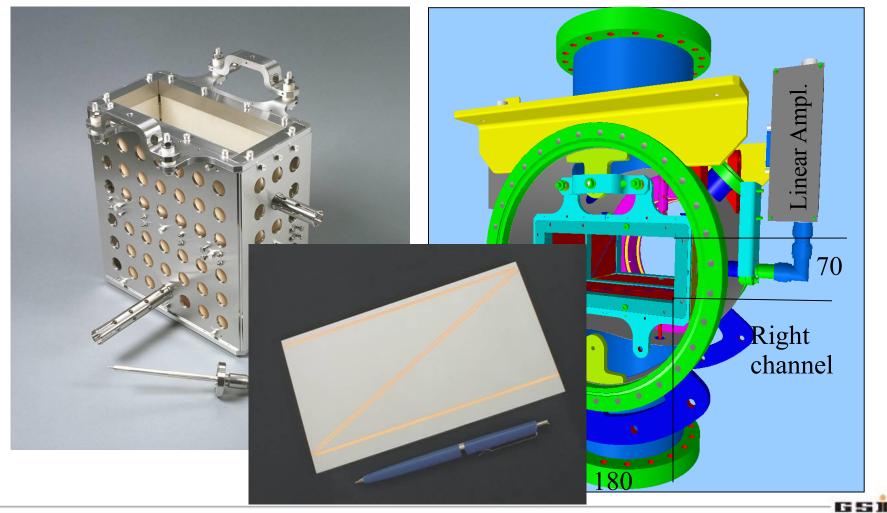
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Ionization Profile Monitor



Technical Realization of a Shoe-Box BPM

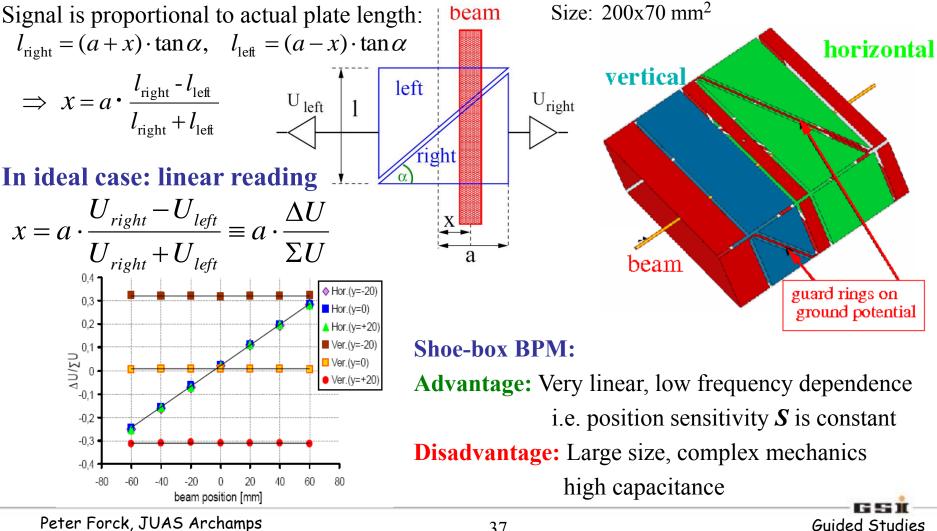
Technical realization at HIT synchrotron of 46 m length for 7 MeV/u \rightarrow 440 MeV/u BPM clearance: 180x70 mm², standard beam pipe diameter: 200 mm.



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Shoe-box BPM for Proton Synchrotrons

Frequency range: 1 MHz $< f_{rf} < 10$ MHz \Rightarrow bunch-length >> BPM length.



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Example of Transfer Impedance for Proton Synchrotron

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The high-pass characteristic for typical synchrotron BPM:

 $U_{im}(\omega) = Z_t(\omega) \cdot I_{heam}(\omega)$ 100 θ 50 phase $|Z_t| = \frac{A}{2\pi a} \cdot \frac{1}{\beta c} \cdot \frac{1}{C} \cdot \frac{\omega / \omega_{cut}}{\sqrt{1 + \omega^2 / \omega_{cut}^2}}$ $|Z_t| [\Omega]$ $\varphi = \arctan(\omega_{cut} / \omega)$ ransfer imp. Parameter for shoe-box BPM: $C = 100 \text{pF}, l = 10 \text{cm}, \beta = 50\%$ $f_{cut} = \omega/2\pi = (2\pi RC)^{-1}$ for *R***=50** $\Omega \Rightarrow f_{cut}$ = 32 MHz

for *R***=1** M $\Omega \Rightarrow f_{cut} = 1.6$ kHz

25 0 10 10⁰ 10^{-1} 10^{-2} high impedance 1 $M\Omega$ 10^{-3} impedance 50 Ω low 10^{-4} $10^{-2} 10^{-1} 10^{0} 10^{1} 10^{2} 10^{3} 10^{3}$ 10 frequency f [MHz]

Large signal strength \rightarrow high impedance Smooth signal transmission \rightarrow 50 Ω

Exercise #8: Signal Estimation for a broad-band BPM 1/2

Assume a shoe-box BPM of length l=20 cm, radius a=10 cm and capacitance C=100 pF The beam velocity is $\beta = 0.5$ and the bunch length is $\sigma_t = 100$ ns.

Assume a position linear sensitivity of S=1/a i.e. $U_{\Delta}/U_{\Sigma} = x/a$.

Calculate the transfer impedance for half-cylindrical plate and termination of $\mathbf{R} = 1 \text{ M}\Omega!$

Calculate the sum voltage U_{Σ} for $I_{beam} = 1 \text{ A}$!

Calculate the different voltage for x = 1 mm displacement!

Result: Transfer impedance for R= 1 MΩ: $Z_t = \frac{l}{\beta cC} \cdot \frac{A}{\pi a} = \frac{1}{\beta cC} = 6.7 \Omega$ with $A = \pi al$ Sum voltage for $I_{beam} = 1$ A: $U_{\Sigma} = 2 Z_t \cdot I_{beam} = 13.3$ V Difference voltage for x = 1 mm: $U_{\Delta} = \frac{x}{a} Z_t \cdot I_{beam} = 67$ mV

What are the corresponding values for a termination with $R = 50 \Omega$? The transfer impedance is not constant, what does it mean? Use $Z_t(50\Omega) = Z_t(1M\Omega)/20$. **Result:** Sum voltage for $I_{beam} = 1$ A: $U_{\Sigma} = 2 Z_t(50 \cdot \Omega) \cdot I_{beam} = 670$ mV

Difference voltage for x = 1 mm: $U_{\Delta} = \frac{x}{a} Z_t (50 \cdot \Omega) \cdot I_{beam} = 3.3 \text{ mV}$

Signal Shape for capacitive BPMs: differentiated \leftrightarrow proportional

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Guided Studies

Depending on the frequency range *and* termination the signal looks different: \rightarrow *High frequency range* $\omega \gg \omega_{cut}$:

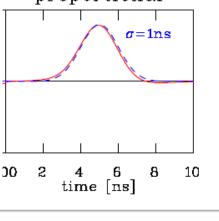
$$Z_{t} \propto \frac{i\omega/\omega_{cut}}{1+i\omega/\omega_{cut}} \rightarrow 1 \Longrightarrow U_{im}(t) = \frac{1}{C} \cdot \frac{1}{\beta c} \cdot \frac{A}{2\pi a} \cdot I_{beam}(t)$$

 $\Rightarrow direct image of the bunch. Signal strength Z_t <math>\propto A/C$ i.e. nearly independent on length > Low frequency range $\omega \ll \omega_{cut}$:

$$Z_{t} \propto \frac{i\omega/\omega_{cut}}{1+i\omega/\omega_{cut}} \rightarrow i\frac{\omega}{\omega_{cut}} \implies U_{im}(t) = R \cdot \frac{A}{\beta c \cdot 2\pi a} \cdot i\omega I_{beam}(t) = R \cdot \frac{A}{\beta c \cdot 2\pi a} \cdot \frac{dI_{beam}}{dt}$$

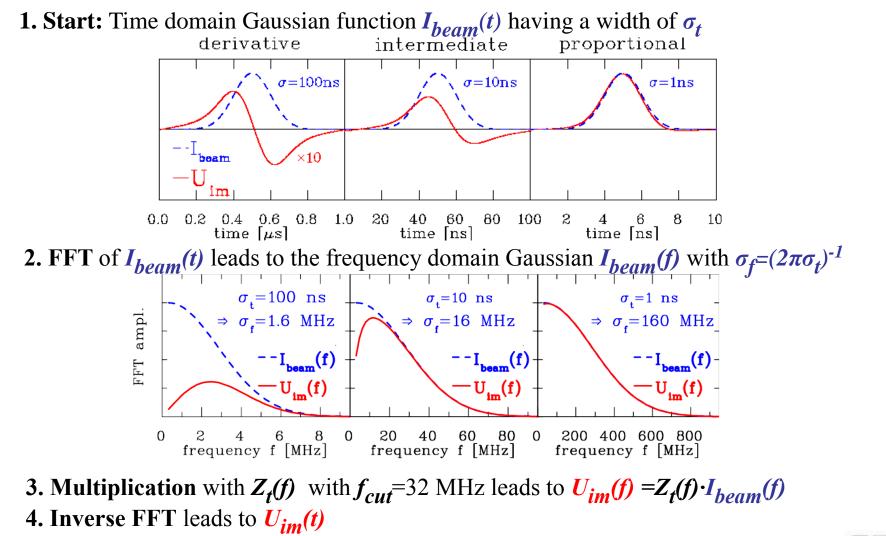
 \Rightarrow derivative of bunch, single strength $Z_t \propto A$, i.e. (nearly) independent on C

Example from synchrotron BPM with 50 Ω termination (reality at p-synchrotron : σ >>1 ns): proportional



Calculation of Signal Shape (here single bunch)

The transfer impedance is used in frequency domain! The following is performed:



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Exercise #8: Signal Estimation for a broad-band BPM 2/2

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Assume a shoe-box BPM of length l=20 cm, radius a=10 cm and capacitance C=100 pF The beam velocity is $\beta = 0.5$ and the bunch length is $\sigma_t = 100$ ns.

Assume a position linear sensitivity of S=1/a i.e. $U_A/U_{\Sigma} = x/a$. Compare the signal strength to the thermal noise (using the theoretical minimum): The thermal noise voltage at T=300 K is given by

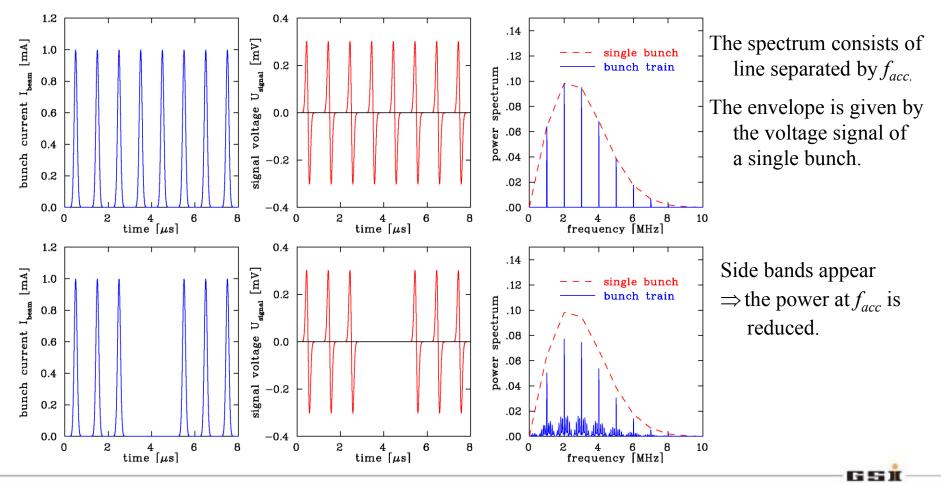
 $U_{noise} = (4k_B \cdot T \cdot R \cdot \Delta f)^{1/2}$ and $k_B = 1.4 \cdot 10^{-23}$ J/K within the bandwidth $\Delta f = 100$ MHz ! Calculate U_{eff} for R = 1 M Ω and R = 50 Ω termination ! **Result:** Thermal noise for R = 1 M Ω : $U_{noise} = \sqrt{4k_B T R \Delta f} = 1.3$ mV Thermal noise for $R = 50 \Omega$: $U_{noise} = \sqrt{4k_B T R \Delta f} = 9.2 \,\mu$ V A displacement of x = 1 mm should be detected. What is the minimum beam current I_{L} to achieve a Signal-to-Noise Ratio S/N=2 !

What is the minimum beam current I_{beam} to achieve a Signal-to-Noise Ratio S/N=2 ! **Result:** For $\mathbf{R} = 1 \text{ M}\Omega \& U_{\Delta} = 2 U_{noise}(1\text{M}\Omega)$: $I_{beam} = \frac{a}{x} \cdot \frac{1}{Z_t(1M\Omega)} \cdot U_{noise} = 40 \text{ mA}$ For $\mathbf{R} = 50 \Omega \& U_{\Delta} = 2 U_{noise}(50\Omega)$: $I_{beam} = \frac{a}{x} \cdot \frac{1}{Z_t(50\Omega)} \cdot U_{noise} = 5.5 \text{ mA}$

(not realistic because BPM from a low pass filter f cut (1M Ω)=1.6 kHz: realistic I_{beam} = 5mA) How can the position resolution be improved significantly? What is the physical reason?

Voltage Spectrum for the BPM and Train of Bunches, R=50 Ω

What is the voltage spectrum for the case of a **bunch train** with $\sigma_t = 100$ ns and $f_{acc} = 1$ MHz? How is the spectrum modified if only part of the buckets are filled?



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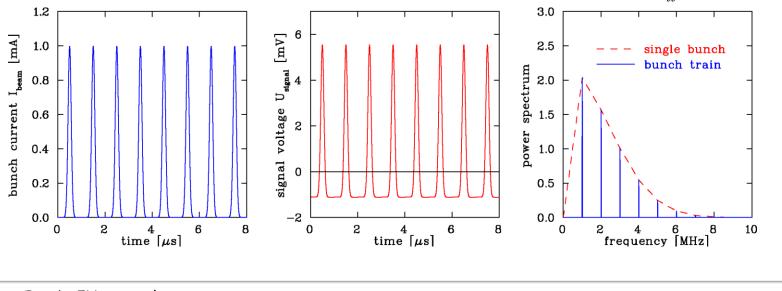
Voltage Spectrum for the BPM and Train of Bunches, R=1 M Ω

What is the spectrum and the signal shape for a termination with $R=1 \text{ M}\Omega$ Sketch and discuss the signal voltage for the case of a bunch train with $\sigma_t = 100 \text{ ns }!$

The cut-off frequency is $f_{cut}=1/(2\pi RC)=1.6 \text{ kHz}$ \Rightarrow the proportional shape is recorded

Signal strength for long bunches is $U_{signal} = Z_t (f > f_{cut}) \cdot I_{beam} = 7 \text{ mV}$ A baseline shift occur i.e. no dc-transmission Reason for this choice: larger signal *independent* on bunch length *However:* larger thermal noise due to $U_{eff} = (4k_B \cdot T \cdot \Delta f \cdot R)^{1/2}$

Guided Studies



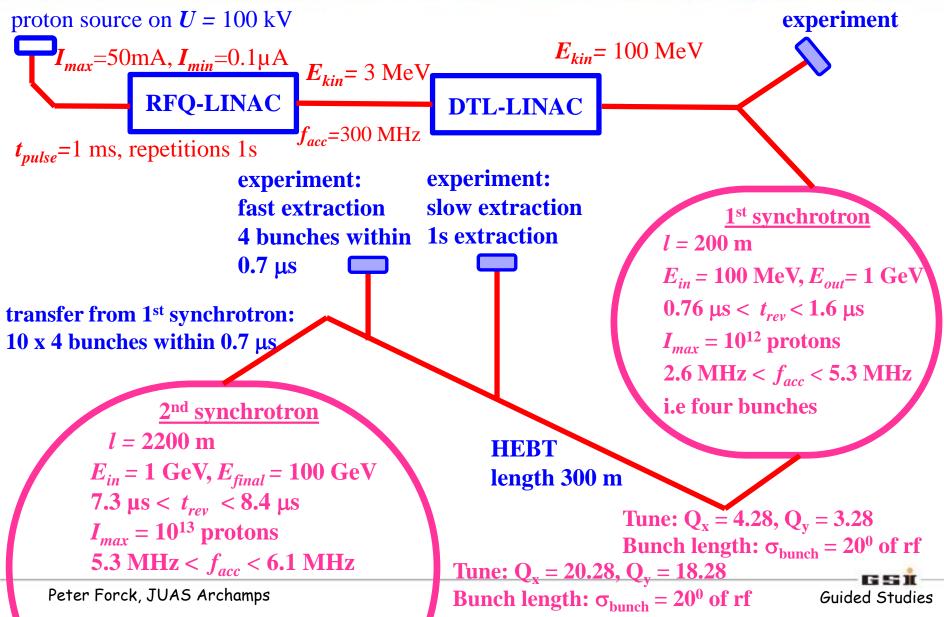
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2.2.4 What is the voltage for the case of a single bunch with $\sigma_t = 1$, 10 and 100 ns and a current of max. value $I_{beam} = 1$ mA? (start with $\sigma_t = 1$ ns, other case only estimation) Assume a value of the transfer impedance $|Z_t(f > f_{cut})| = 7 \Omega$ above $f_{cut} = 32$ MHz.

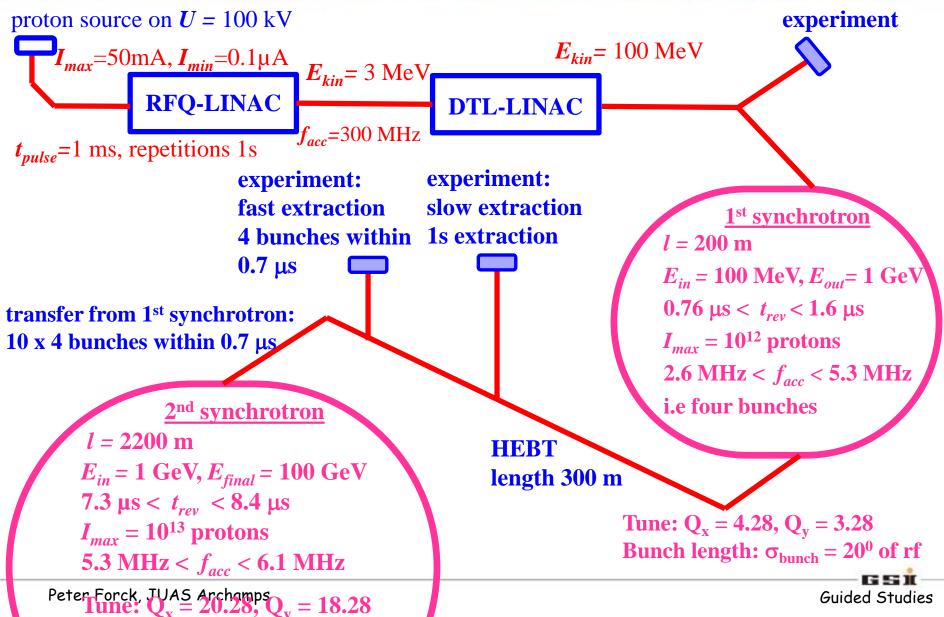
➢ For short bunches σ_t=1 ns → σ_f=1/2πσ_t = 160 MHz
i.e. main component above f_{cut} ⇒ proportional shape
⇒ U_{signal}=Z_t (f>f_{cut}) ·I_{beam}=7 mV for the σ_t=1 ns case

For long bunches with σ_t=100 ns → σ_f=1/2πσ_t = 1.6 MHz
i.e. all frequencies below f_{cut} ⇒ derivative shape
⇒ U_{signal}≈ 0.3 mV for the σ_t=100 ns case (i.e. a factor 23 lower!)
For the σ_t=10 ns the signal must be calculated:
⇒ U_{signal}≈ 3 mV for the σ_t=10 ns case









Exercise #6: Transverse profile by flying wire scanner

Assume a beam of 10^{12} protons at 1GeV stored in a synchrotron. The beam size 10x10 mm with ρ_{beam} =const (for simplification), the revolution time is 1.0 µs. The wire is made of Carbon with 50x50 µm and scanned with v=10 m/s. [Carbon is light material of $\rho=2.2$ g/cm³ density therefore low stopping power.] The energy loss is dE/dx=4.29 MeV/cm.

Calculate the relative energy loss per passage through the wire!

Calculate the average energy loss during the scan! How many passages an ion does in average? Is this device nearly 'non-destructive' \Leftrightarrow Are the particles lost?

The maximum power rate to prevent for destruction is 1 W/mm.

Is the wire destroyed?

Repeat the same calculation assuming 10⁹ stored Uranium ions!

The energy loss is now dE/dx=35640 MeV/cm.

Why is the energy loss so much larger?

Are the particles loss? Is the wire destroyed?

What happens for not fully stripped ions (i.e. ions with some bound electrons)? What is an appropriate method of profile determination for the Uranium case?